



### 20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current

#### **Features**

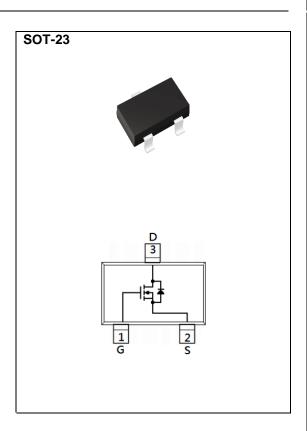
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@4.5V, I<sub>D</sub>@5.2A<36mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_D@3.2A<52m\Omega$
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@1.8V, I<sub>D</sub>@1.5A<92mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

5.2A

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	20	V	
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 12		
Continuous Drain Current(Note 4)		I <sub>D</sub>	5.2	A	
Pulsed Drain Current(Note 1)		I <sub>DM</sub>	20.8		
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3,4)</sup>		Reja	100	°C/W	





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			_			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub> V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.5	0.77	1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5.2A	-	29	36	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.2A	-	39	52	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.5A	-	58	92	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 5)</sup>						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =5.2A, V <sub>GS</sub> =4.5V (Note 1,2)	-	4.1	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.1	-	
Gate-Drain Charge	$Q_{gd}$		-	0.7	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ	-	396	-	pF
Output Capacitance	Coss		-	54	-	
Reverse Transfer Capacitance	Crss		-	40	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 40\/ L 50A	-	14	-	
Turn-On Rise Time	tr	$V_{DD}$ =10V, $I_{D}$ =5.2A, $V_{GS}$ =4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)		10		ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	30	-	
Turn-Off Fall Time	tf			7		
Drain-Source Diode						
Maximum Continuous Drain-Source					1.5	_
Diode Forward Current	IS	ls		-	1.0	A
Diode Forward Voltage	$V_{\text{SD}}$	Is=1A, V <sub>GS</sub> =0V	-	0.75	1.2	V

#### NOTES:

- 1. Pulse width $\leq$ 300us, Duty cycle $\leq$ 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

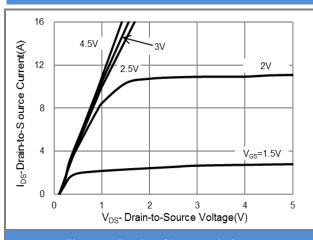


Fig.1 On-Region Characteristics

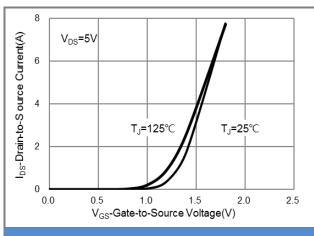


Fig.2 Transfer Characteristics

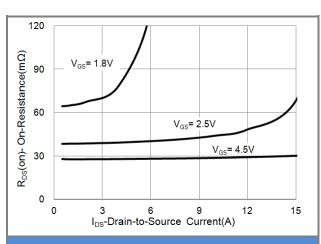


Fig.3 On-Resistance vs. Drain Current

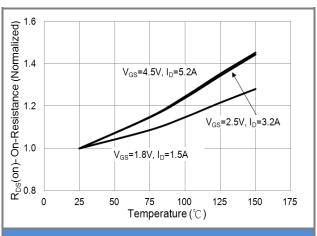
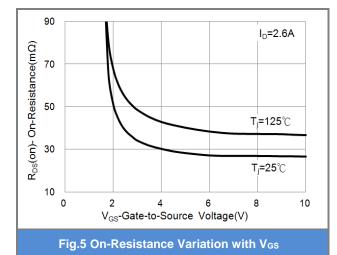
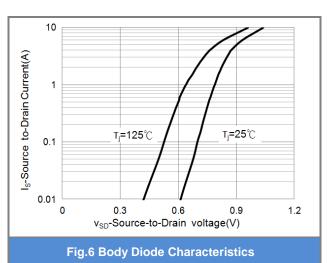


Fig.4 On-Resistance vs. Junction temperature









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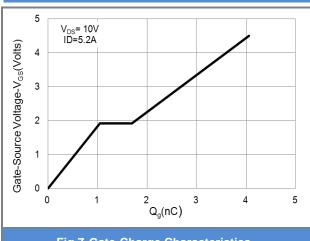


Fig.7 Gate-Charge Characteristics

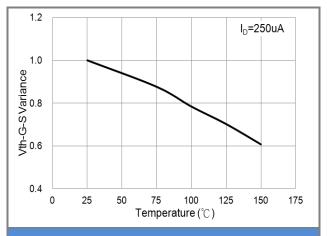


Fig.8 Threshold Voltage Variation with Temperature

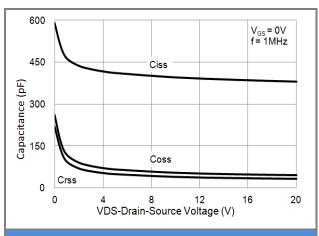


Fig.9 Capacitance vs. Drain-Source Voltage

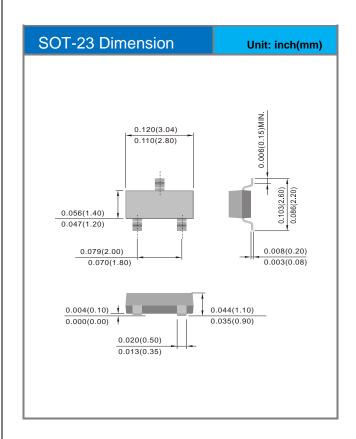


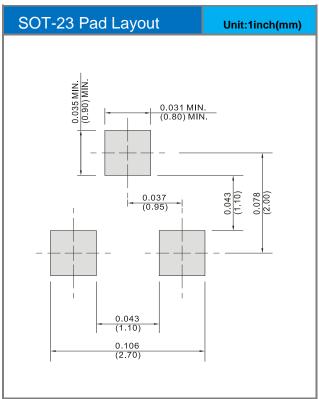


### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3414-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A14	Halogen free RoHS compliant

## **Packaging Information & Mounting Pad Layout**









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